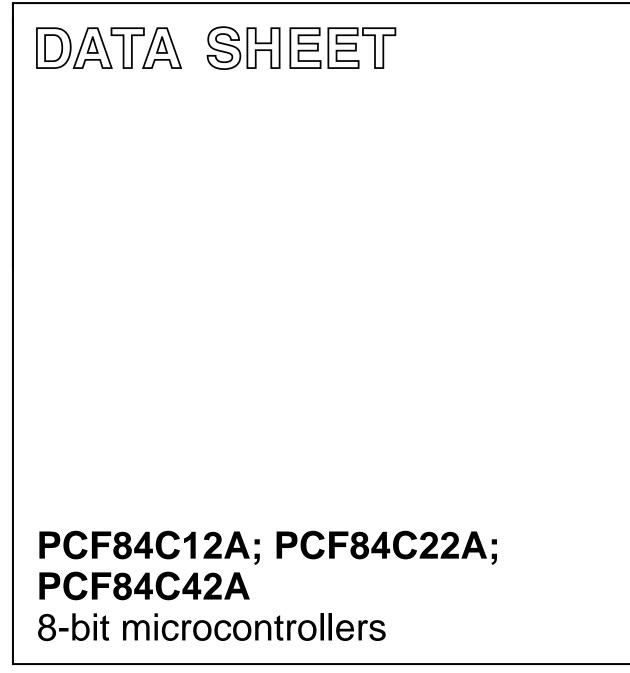
INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Apr 04 File under Integrated Circuits, IC14 1996 Nov 20



## PCF84C12A; PCF84C22A; **PCF84C42A**

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#### 1 FEATURES

- Manufactured in silicon gate CMOS process
- 8-bit CPU, ROM, RAM, I/O in a 20-lead package
- 1 kbyte ROM (PCF84C12A)
- 2 kbyte ROM (PCF84C22A)
- 4 kbyte ROM (PCF84C42A)
- 64 byte RAM
- Over 100 instructions (based on MAB8048) all of 1 or 2 cycles
- 13 quasi-bidirectional I/O port lines
- 8-bit programmable timer/event counter 1
- Two single-level vectored interrupts:
  - external
  - 8-bit programmable timer/event counter 1
- Two test inputs, one of which also serves as the external interrupt input
- Stop and Idle modes
- Supply voltage: 2.5 to 5.5 V
- Clock frequency: 1 to 16 MHz
- Operating temperature: -40 to +85 °C.

#### 3 ORDERING INFORMATION (see note 1)

## PCF84C12A; PCF84C22A; PCF84C42A

#### 2 GENERAL DESCRIPTION

This data sheet details the specific properties of the PCF84C12A, PCF84C22A and PCF84C42A. The shared properties of the PCF84CxxxA family of microcontrollers are described in the *"PCF84CxxxA family"* data sheet, which should be read in conjunction with this publication. Note that the devices described in this data sheet do not feature I<sup>2</sup>C-bus compatibility or derivative logic, so the information given in the family data sheet about these features can be ignored.

The PCF84C12A, PCF84C22A and PCF84C42A are general purpose CMOS microcontrollers with 1 kbyte, 2 kbytes and 4 kbytes of program memory, respectively. They include 64 bytes of RAM and 13 I/O port lines. The instruction set is based on the MAB8048 and is a sub-set of that listed in the *"PCF84CxxxA family"* data sheet.

TYPE NUMBER	PACKAGE				
ITPE NOWBER	NAME	DESCRIPTION	VERSION		
PCF84C12AP	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1		
PCF84C22AP					
PCF84C42AP	•				
PCF84C12AT	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1		
PCF84C22AT					
PCF84C42AT					

#### Note

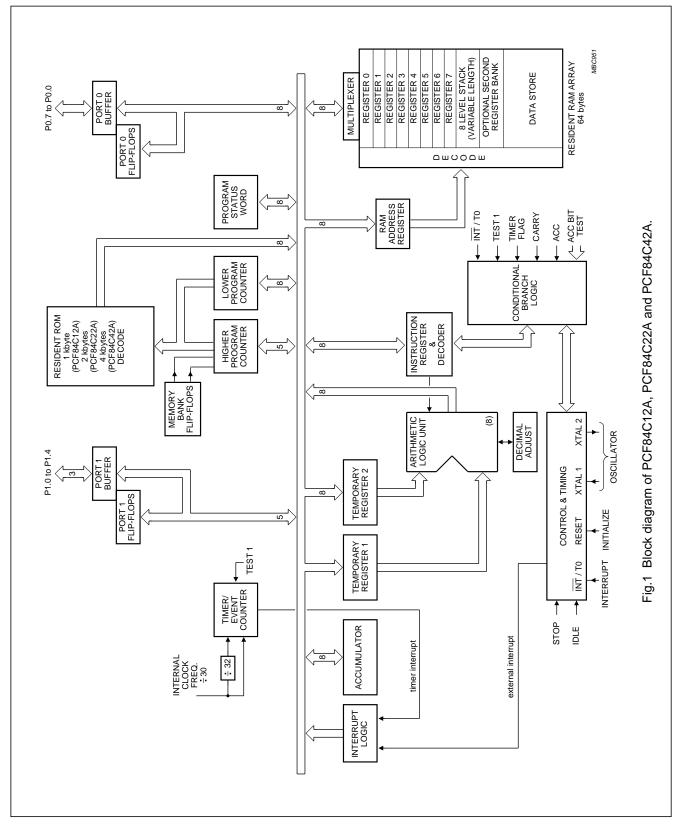
1. Please refer to the Order Entry Form (OEF) for these devices for the full type number to use when ordering. This type number will also specify the required program and ROM mask options.

Product specification

### 8-bit microcontrollers

## PCF84C12A; PCF84C22A; PCF84C42A

#### 4 BLOCK DIAGRAM



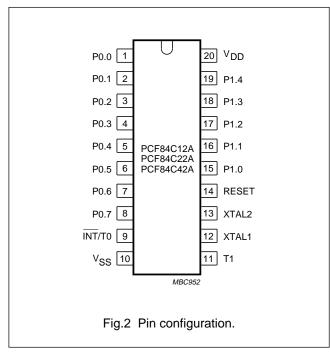
PCF84C42A

PCF84C12A; PCF84C22A;

### 8-bit microcontrollers

#### 5 PINNING INFORMATION

5.1 Pinning



#### 6 INSTRUCTION SET

Since the I<sup>2</sup>C-bus interface, Port 2 and derivative logic are not provided, instructions associated with these functions are not available.

ROM space is restricted to 1 kbyte for the PCF84C12A, 2 kbytes for the PCF84C22A and 4 kbytes for the PCF84C42A. Therefore, the instructions SEL MB1/2/3 for the PCF84C12A and PCF84C22A, and the instructions SEL MB2/3 for PCF84C42A should be avoided as they would define non-existing program memory banks.

As RAM space is limited to 64 bytes, care should be taken to avoid accesses to non-existing RAM locations.

Refer to the *"PCF84CxxxA family"* data sheet, for a complete description of the instruction set.

#### 5.2 Pin description

Table 1 DIP20 and SO20 packages

SYMBOL	PIN	TYPE	DESCRIPTION
P0.0 to P0.7	1 to 8	I/O	8 bits of Port 0: 8-bit quasi-bidirectional I/O port
INT/T0	9	I	Interrupt/Test 0
V <sub>SS</sub>	10	Р	ground
T1	11	I	Test 1/count input of 8-bit timer/event counter 1
XTAL1	12	I	crystal oscillator input or external clock input
XTAL2	13	0	crystal oscillator output
RESET	14	I	Reset input
P1.0 to P1.4	15 to 19	I/O	4 bits of Port 1: 4-bit quasi-bidirectional I/O port
V <sub>DD</sub>	20	Р	positive supply

## PCF84C12A; PCF84C22A; PCF84C42A

#### 7 ROM MASK OPTIONS

ROM CODE		OPTION			
Program/data	1 kbyte for the	Any mix of instructions and data up to ROM size of 1 kbyte for the PCF84C12A, 2 kbytes for the PCF84C22A and 4 kbytes for the PCF84C42A.			
Port Output					
P0.0 to P0.7	standard	open-drain	push-pull		
P1.0 to P1.4	standard	open-drain	push-pull		
Port State after reset					
P0.0 to P0.7	set	reset	-		
P1.0 to P1.4	set	reset	-		
Oscillator					
Transconductance	LOW (g <sub>mL</sub> )	MEDIUM (g <sub>mM</sub> )	HIGH (g <sub>mH</sub> )		

#### 8 HANDLING

Inputs and outputs are protected against electrostatic discharge in normal handling. However, it is good practice to take normal precautions appropriate to handling MOS devices. See "Data Handbook IC14, Section: Handling MOS devices".

#### 9 LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>DD</sub>	supply voltage	-0.5	+7	V
VI	all input voltages	-0.5	V <sub>DD</sub> + 0.5	V
I <sub>I</sub>	DC input current	-10	+10	mA
Io	DC output current except Port 1 output LOW	-10	+10	mA
P <sub>tot</sub>	total power dissipation	-	125	mW
Po	power dissipation per output	-	30	mW
I <sub>DD</sub>	supply current	-50	+50	mA
I <sub>SS</sub>	ground supply current	-100	+50	mA
T <sub>stg</sub>	storage temperature range	-55	+150	°C
Tj	operating junction temperature	-	90	°C

## PCF84C12A; PCF84C22A; PCF84C42A

#### 10 DC CHARACTERISTICS

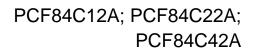
 $V_{DD}$  = 2.5 to 5.5 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = -40 to +85 °C; all voltages with respect to  $V_{SS}$ ; unless otherwise specified.

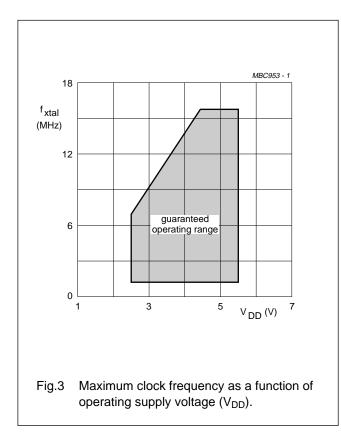
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>DD</sub>	operating supply voltage	see Fig.3	2.5	-	5.5	V
I <sub>DD</sub>	operating supply current	note 1; see Figs 4 and 5				
		$V_{DD} = 3 \text{ V}; \text{ f}_{xtal} = 3.58 \text{ MHz} (g_{mL})$	_	0.3	0.6	mA
		$V_{DD} = 5 \text{ V}; \text{ f}_{xtal} = 10 \text{ MHz} (g_{mL})$	-	1.1	3.0	mA
		$V_{DD} = 5 \text{ V}; \text{ f}_{xtal} = 16 \text{ MHz} (g_{mM})$	_	1.7	5.0	mA
		$V_{DD} = 5 \text{ V}; \text{ f}_{xtal} = 16 \text{ MHz} (g_{mH})$	_	2.5	6.0	mA
I <sub>DD(idle)</sub>	supply current (Idle mode)	note 1; see Figs 6 and 7				
		$V_{DD} = 3 \text{ V}; \text{ f}_{xtal} = 3.58 \text{ MHz} (g_{mL})$	-	0.2	0.4	mA
		$V_{DD} = 5 \text{ V}; \text{ f}_{xtal} = 10 \text{ MHz} (g_{mL})$	_	0.8	1.6	mA
		$V_{DD} = 5 \text{ V}; \text{ f}_{xtal} = 16 \text{ MHz} (g_{mM})$	_	1.2	4.0	mA
		$V_{DD} = 5 \text{ V}; \text{ f}_{\text{xtal}} = 16 \text{ MHz} (g_{\text{mH}})$	_	1.7	5.0	mA
I <sub>DD(stp)</sub>	supply current (Stop mode)	$V_{DD}$ = 2.5 V; notes 1 and 2; see Fig.8	-	1.2	10	μA
Inputs			·			-
V <sub>IL</sub>	LOW level input voltage		0	-	0.3V <sub>DD</sub>	V
V <sub>IH</sub>	HIGH level input voltage		0.7V <sub>DD</sub>	-	V <sub>DD</sub>	V
ILI	input leakage	$V_{SS} \leq V_1 \leq V_{DD}$	-1	-	+1	μA
Outputs			·			-
I <sub>OL</sub>	LOW level output sink current	$V_{DD} = 5 \text{ V}; V_{O} = 0.4 \text{ V}; \text{ see Fig.9}$	1.6	12	-	mA
I <sub>OH</sub>	HIGH level pull-up output	$V_{DD} = 5 \text{ V}; V_{O} = 3.5 \text{ V}; \text{ see Fig.10}$	40	100	-	μA
	source current	$V_{DD} = 5 \text{ V}; V_{O} = 0 \text{ V}; \text{ see Fig.10}$	_	-140	-400	μA
I <sub>OH1</sub>	HIGH level push-pull output source current	$V_{DD} = 5 V; V_{O} = 4.6 V; see Fig.11$	-1.6	-7	-	mA
Oscillato	r (see Fig.12)					
9 <sub>mL</sub>	LOW transconductance	$V_{DD} = 5 V$	0.2	0.4	1.0	mS
9 <sub>mM</sub>	MEDIUM transconductance	$V_{DD} = 5 V$	0.9	1.6	3.2	mS
9 <sub>mH</sub>	HIGH transconductance	$V_{DD} = 5 V$	3.0	4.5	9.0	mS
R <sub>F</sub>	feedback resistor		0.3	1.0	3.0	MΩ

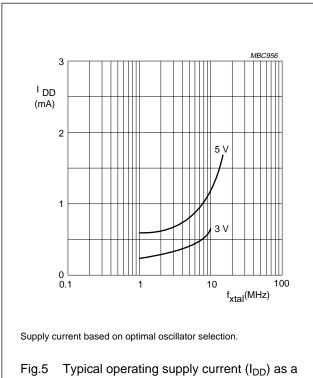
Notes

1. V<sub>IL</sub> = V<sub>SS</sub>; V<sub>IH</sub> = V<sub>DD</sub>; open drain outputs connected to V<sub>SS</sub>; all other outputs, including XTAL2, open (typical values at 25 °C with crystal connected between XTAL1 and XTAL2).

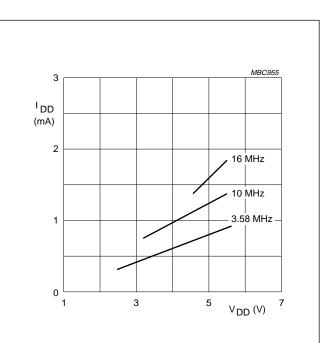
V<sub>IL</sub> = V<sub>SS</sub>; V<sub>IH</sub> = V<sub>DD</sub>; RESET and T1 at V<sub>SS</sub>; INT/T0 at V<sub>DD</sub>; crystal connected between XTAL1 and XTAL2; open drain outputs connected to V<sub>SS</sub>; all other outputs open.





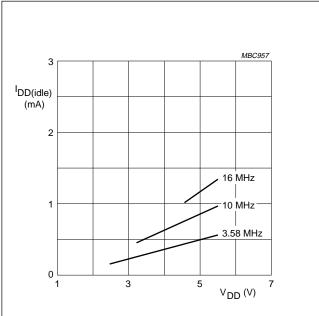


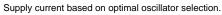
g.5 I ypical operating supply current (I<sub>DD</sub>) a function of clock frequency (f<sub>xtal</sub>).



Supply current based on optimal oscillator selection.

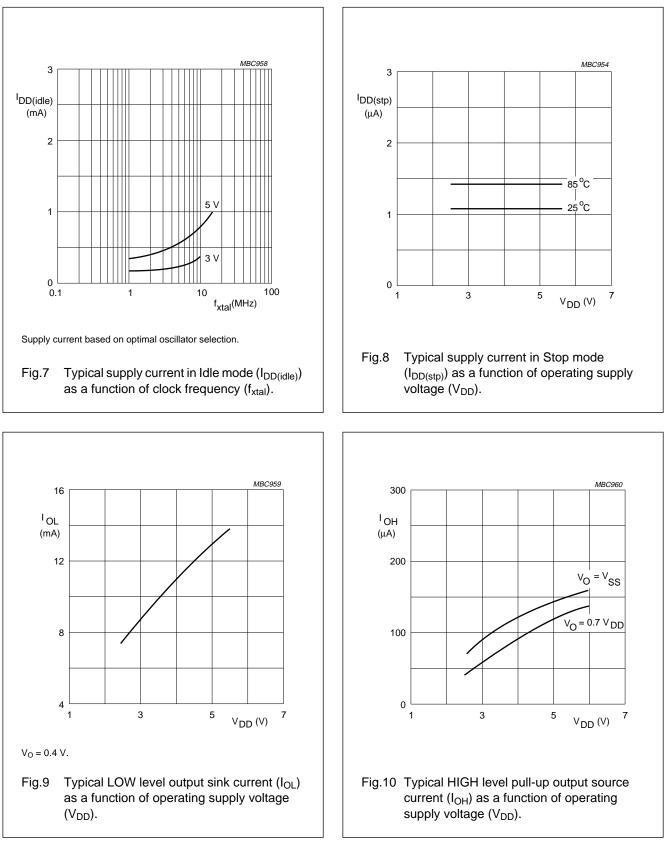
Fig.4 Typical operating supply current  $(I_{DD})$  as a function of operating supply voltage  $(V_{DD})$ .



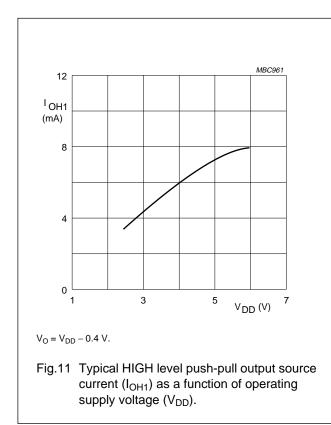


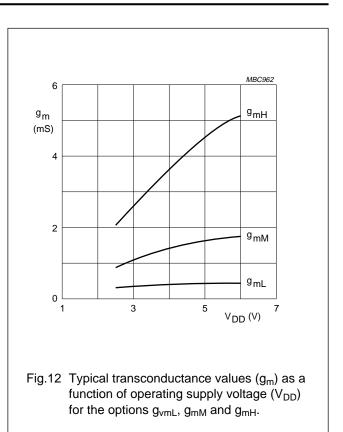
 $\label{eq:Fig.6} \begin{array}{l} \mbox{Typical supply current in Idle mode } (I_{DD(idle)}) \\ \mbox{ as a function of operating supply voltage} \\ (V_{DD}). \end{array}$ 

## PCF84C12A; PCF84C22A; PCF84C42A



## PCF84C12A; PCF84C22A; PCF84C42A





#### 11 AC CHARACTERISTICS

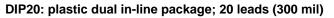
 $V_{DD}$  = 2.5 to 5.5 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = -40 to +85 °C; all voltages with respect to  $V_{SS}$ ; unless otherwise specified.

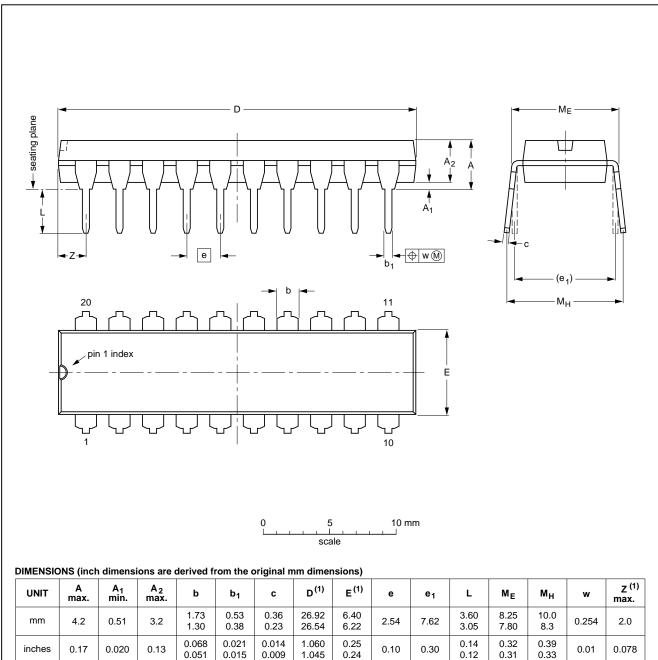
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t <sub>r</sub>	rise time all outputs	$V_{DD} = 5 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}; \text{ C}_{L} = 50 \text{ pF}$	-	30	-	ns
t <sub>f</sub>	fall time all outputs	$V_{DD} = 5 \text{ V}; \text{ T}_{amb} = 25 ^{\circ}\text{C}; \text{ C}_{L} = 50 \text{ pF}$	-	30	_	ns
f <sub>xtal</sub>	clock frequency	see Fig.3	1	-	16	MHz

### PCF84C12A; PCF84C22A; PCF84C42A

### 8-bit microcontrollers

#### 12 PACKAGE OUTLINES





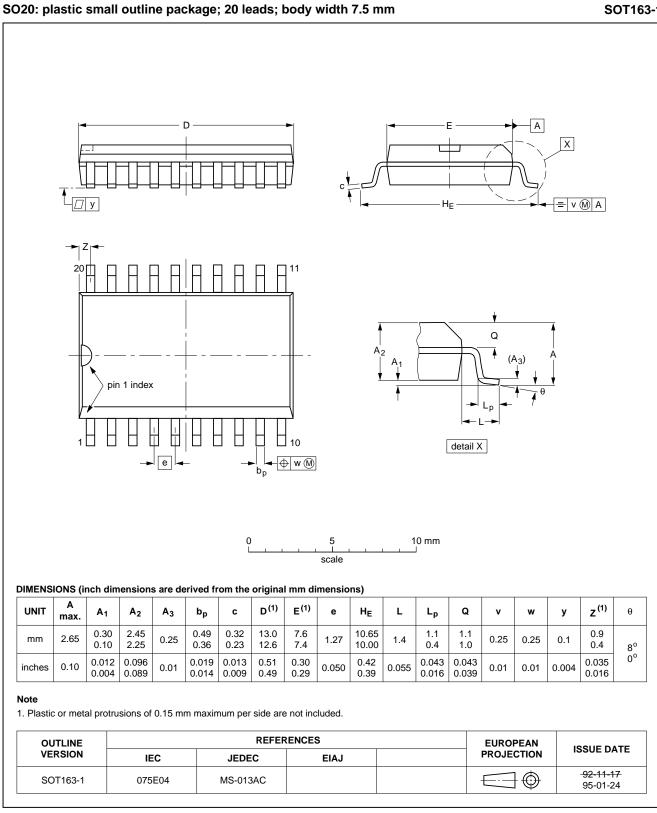
#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT146-1			SC603			<del>92-11-17</del> 95-05-24	

SOT146-1

## PCF84C12A; PCF84C22A; PCF84C42A



SOT163-1

## PCF84C12A; PCF84C22A; PCF84C42A

#### 13 SOLDERING

#### 13.1 Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

#### 13.2 DIP

13.2.1 SOLDERING BY DIPPING OR BY WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg max}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### 13.2.2 REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

#### 13.3 SO

#### 13.3.1 REFLOW SOLDERING

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45  $^{\circ}$ C.

#### 13.3.2 WAVE SOLDERING

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### 13.3.3 REPAIRING SOLDERED JOINTS

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

## PCF84C12A; PCF84C22A; PCF84C42A

#### 14 DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
more of the limiting values of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.
Application information	

Where application information is given, it is advisory and does not form part of the specification.

#### 15 LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

## PCF84C12A; PCF84C22A; PCF84C42A

NOTES

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